



# **AUTOMATIZED DARK CURRENT MEASUREMENT SYSTEM FOR IRRADIATED SIPM DETECTORS IN COSY**

MARCH 2020 | ANOOP N KOUSHIK

# OUTLINE

I) Introduction

II) SiPM Dark Current

III) Healthy vs Irradiated

IV) Experimental Setup

- Basic (Manual)
- Semi-automatic
- Completely automatized

V) Results

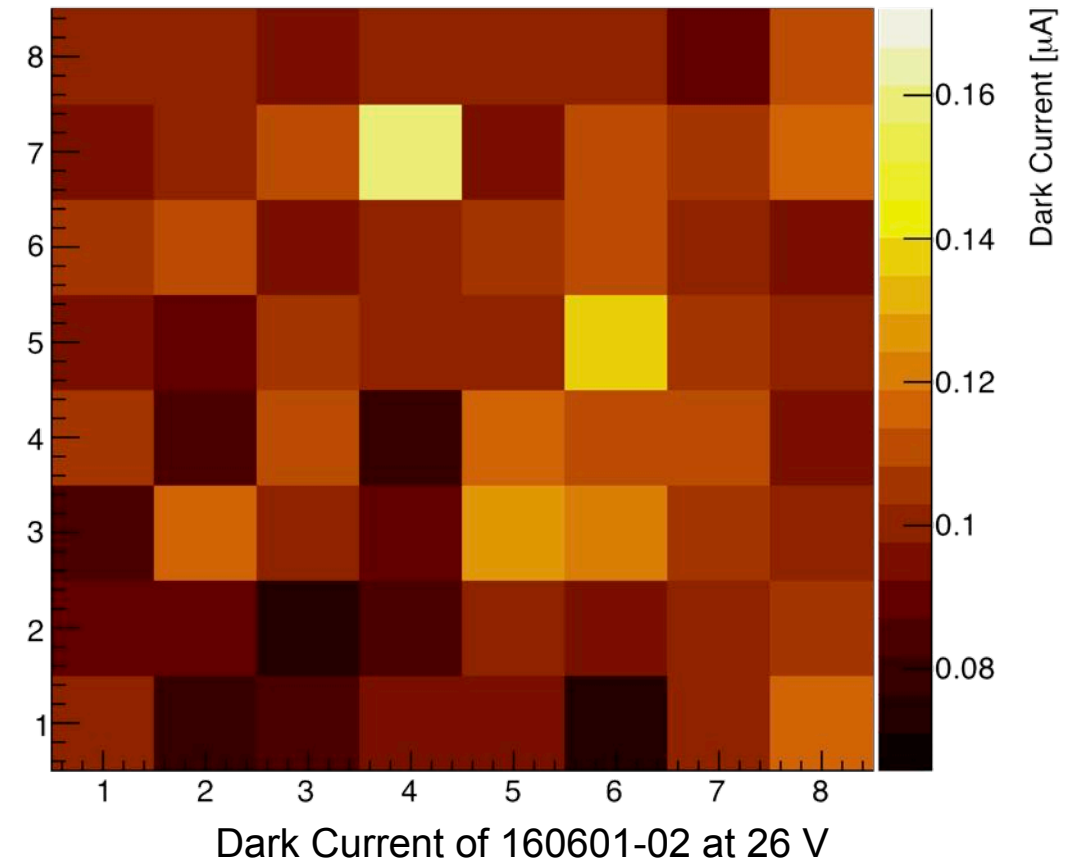
VI) Current Issues and Future Plans

# INTRODUCTION

- SiPMs are used in the polarimeter in CoSy at Forschungszentrum Jülich along with the LYSO crystal.
- A photon, as a result of the recombination in the crystal, triggers the APD (Avalanche Photo-Diode) recording the event and the energy of the photon.
- SiPM array is a matrix of 16 (8x8) of such APD which are set to geiger mode
- For this presentation, all the SiPM array modules used and the results obtained are from  
**SensL ArrayJ 30020 8x8**

# SIPM DARK CURRENT

- Dark Current is current generated in the absence of photon
  - Phenomena such as thermal excitation, defects in crystal lattice etc.
- Dark current is the noise in the signal.
- Range of dark current in our lab conditions:
  - 1 to 10  $\mu\text{A}$  @ 26 V
- \* Dark current of 160601-02 @ 26 V is 6.471  $\mu\text{A}$



# HEALTHY VS IRRADIATED

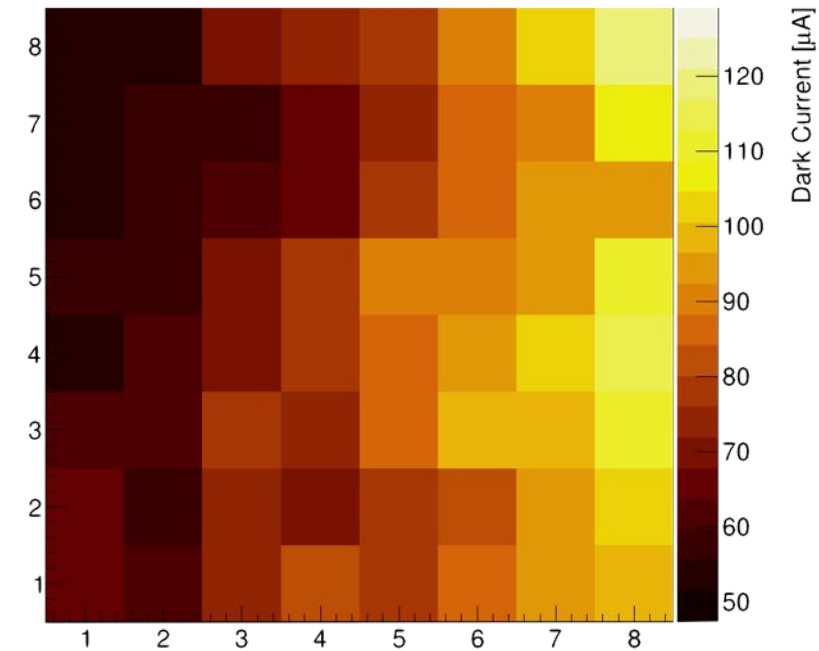
Healthy SiPM	Irradiated SiPM
Low dark current $\Rightarrow$ low noise	High dark current $\Rightarrow$ high noise
Very good resolution	Very low resolution
Reading are consistent over time	Reading varies because of annealing over time
In lab conditions: 1 - 10 $\mu\text{A}$ at 26 V	After irradiation: 500 - 7000 $\mu\text{A}$ at 26 V

Note: Values are for 8x8 SiPM matrix

# INSPIRATION

- SiPMs in CoSy are exposed to radiation
- SiPMs are not completely radiation hard
- To understand the effects and to know the limitations of the device
- Need instrumentation to study irradiated SiPM?
  - Dark current of the SiPM matrix
  - Dark current of individual SiPM
  - Ability to control voltage
  - Observe the change in dark current
  - Observe the radiation effects (patterns)
  - Observe annealing effects

Dark Current Map: Dark Current Map of SiPM 161123-28 at  $V_{\text{Bias}} = 26\text{V}$



# EXPERIMENTAL SETUP

## Ideas and goals to achieve

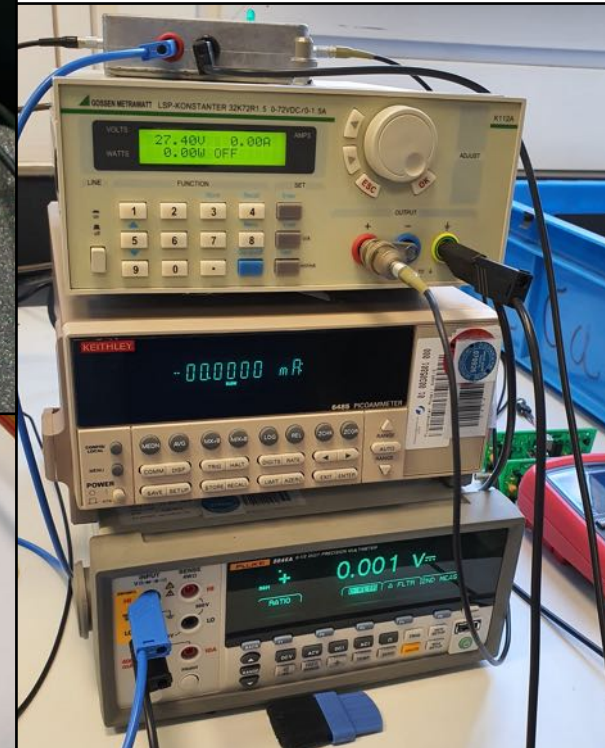
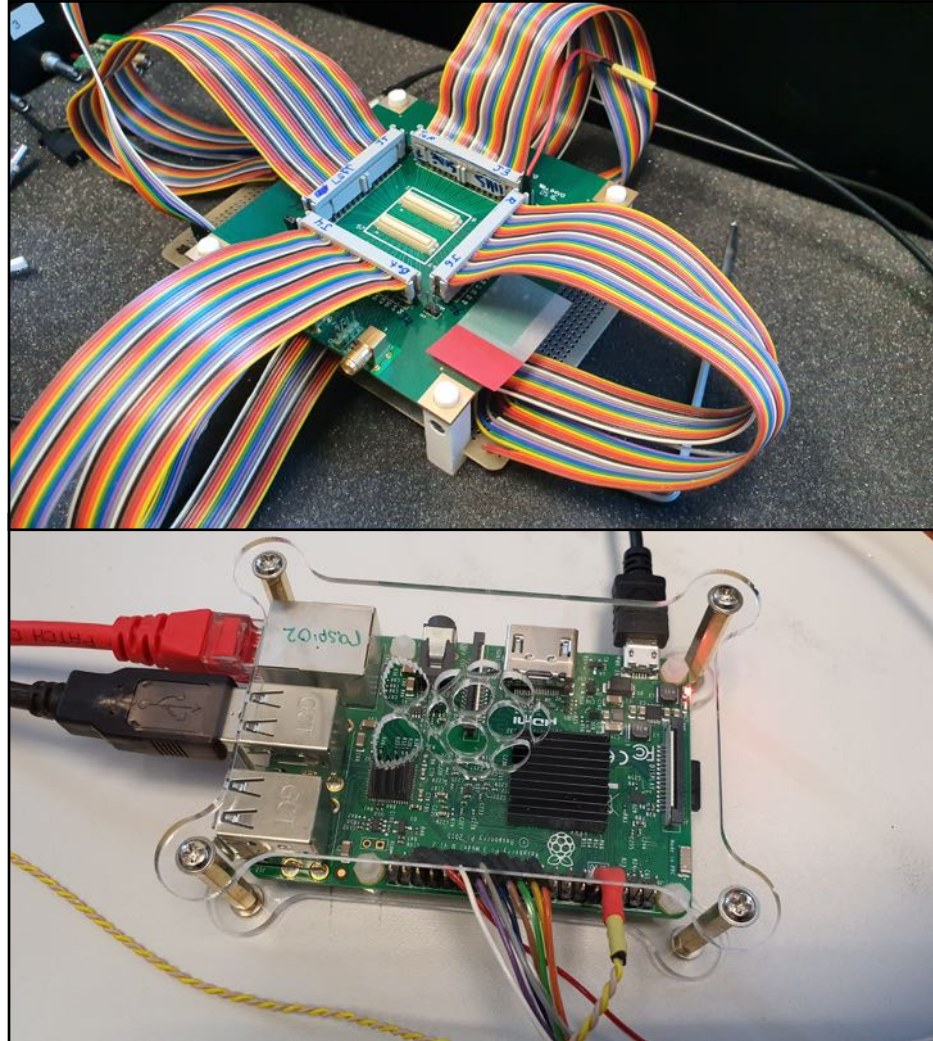
- Measure the dark current of each SiPM in the matrix
- Compare the analysis data to the old datasets (also in batch)
- Generate reports of one or several SiPMs along with their comparisons
- Change the supply voltage to the SiPMs
- Monitor recorded data live on web browser during the measurements
- Workaround for the heating issues during measurements
- Timely measurements without human intervention



# EXPERIMENTAL SETUP

## Basic setup

- SiPM matrix has 64 SiPMs.
- Channeling of each SiPM from SensL SiPM development board with 5 multiplexer was designed by Dr. Fabian Müller
- Controlled by Raspberry Pi
- Measurement script on python
- Instruments:
  - Pico-ammeter - Keithley
  - Voltmeter - Fluke
  - Power supply - GW

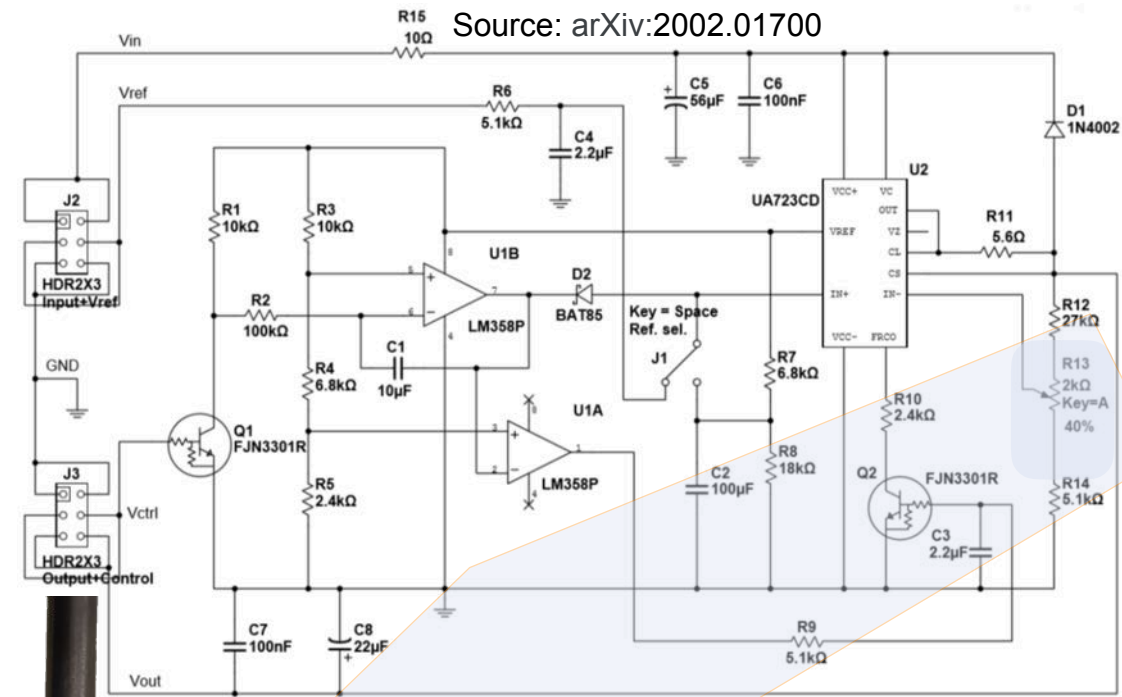




# EXPERIMENTAL SETUP

## Manual device

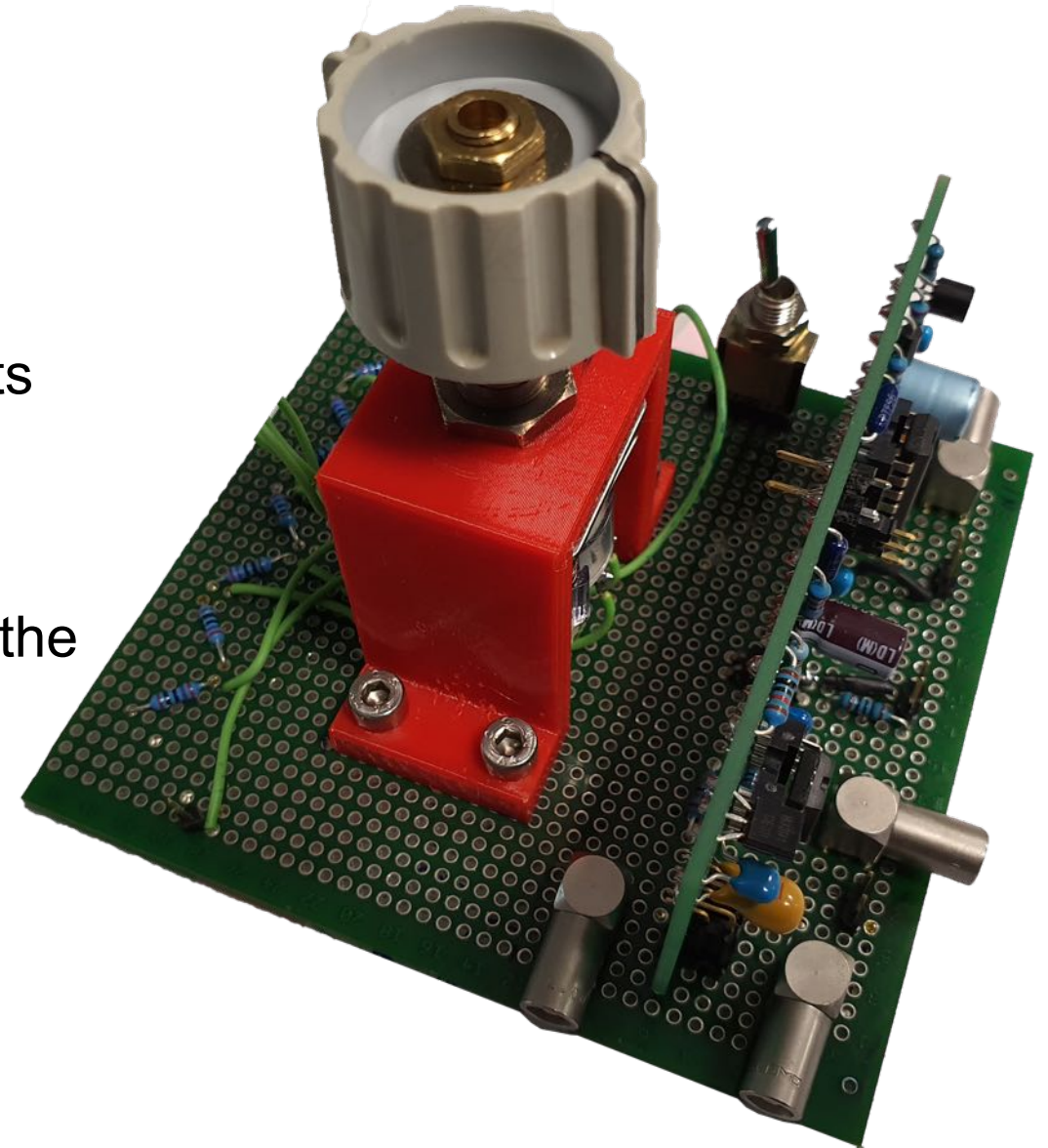
- Onboard potentiometer was replaced by a switch connecting a series of resistors
- Housing for the switch was printed
- Voltage could be changed by rotating the switch
- Separate switch to turn on and turn off the power supply



# EXPERIMENTAL SETUP

## Manual device

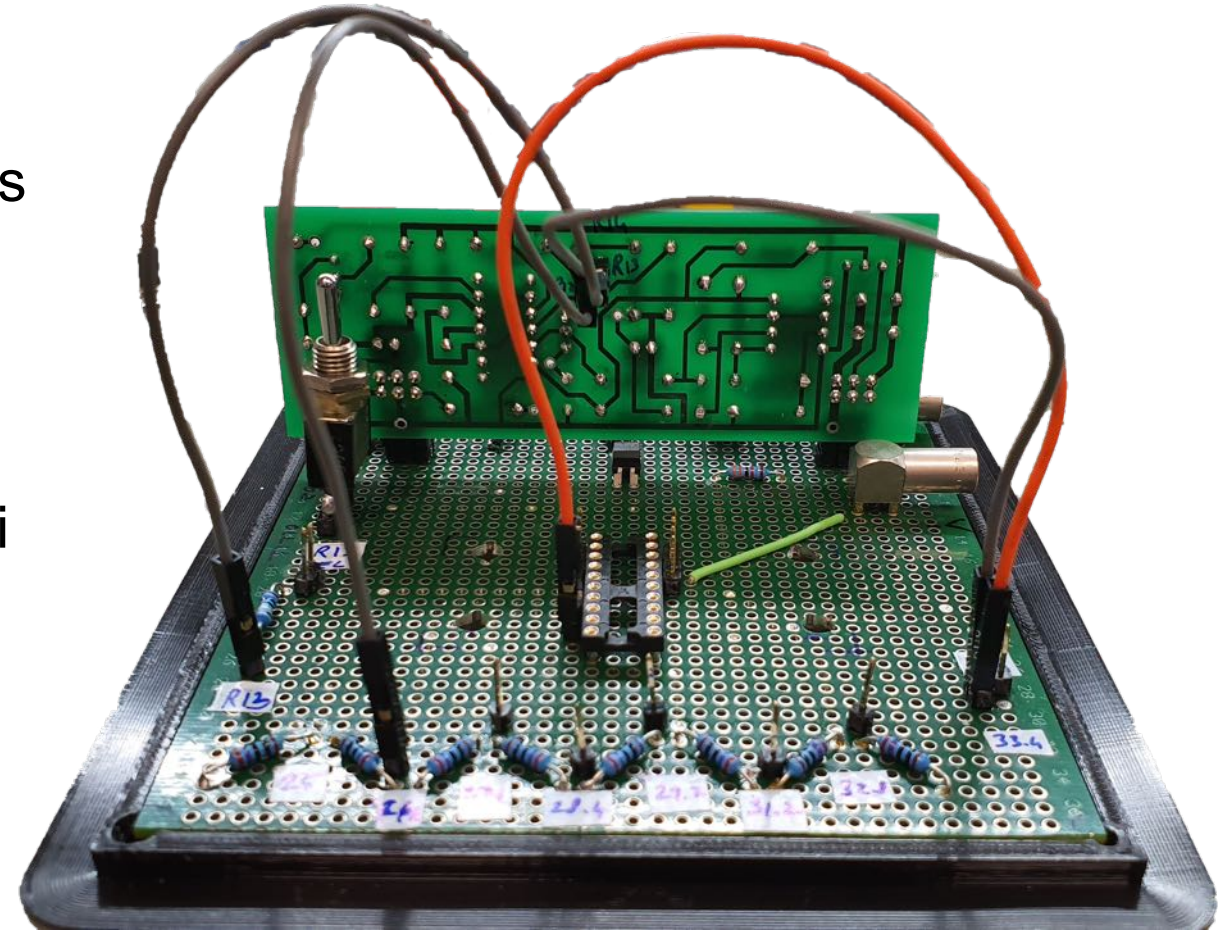
- Issues with this setup
  - Manually switching for several measurements would be tedious
  - Connector in the switch had bad contact
  - Switch added an extra varying resistance to the circuit



# EXPERIMENTAL SETUP

## Semi-automatic device

- Switch was replaced by a series of connectors around the resistors
- The connection was made manually by wires with option to add a multiplexer
- Power on / off was controlled by Raspberry Pi
- Issues:
  - Still manual to change voltage

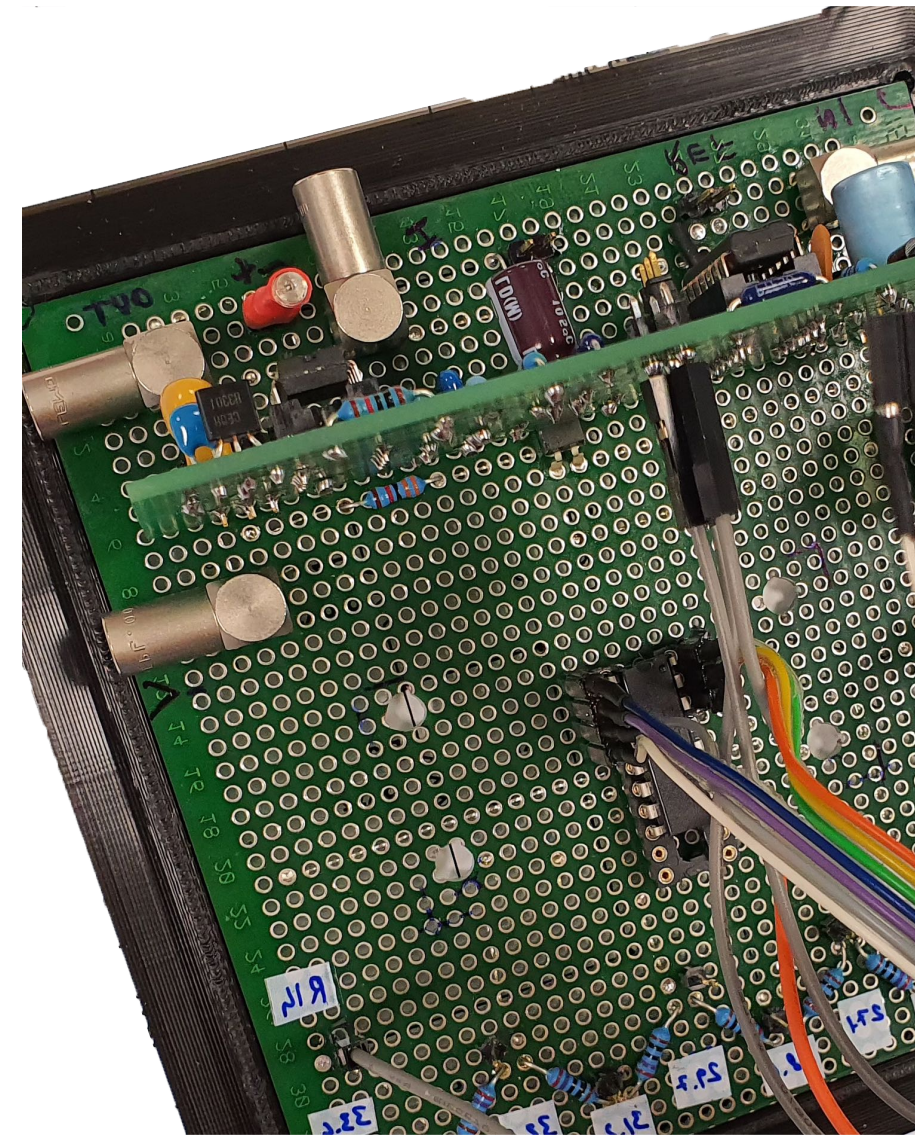




# EXPERIMENTAL SETUP

## Automatic device

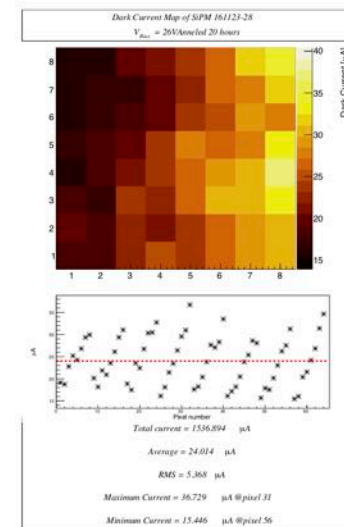
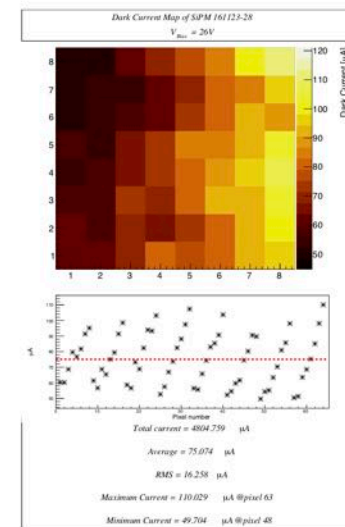
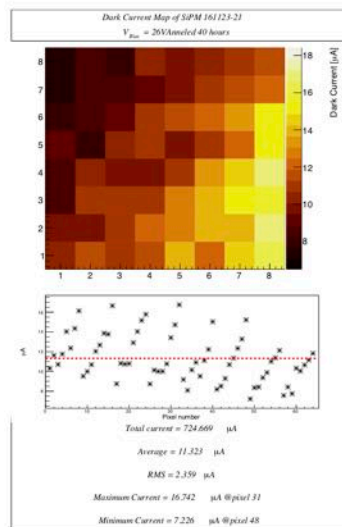
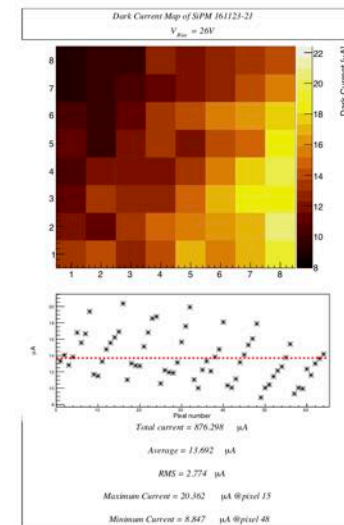
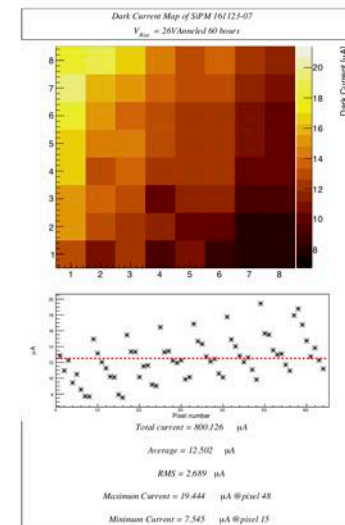
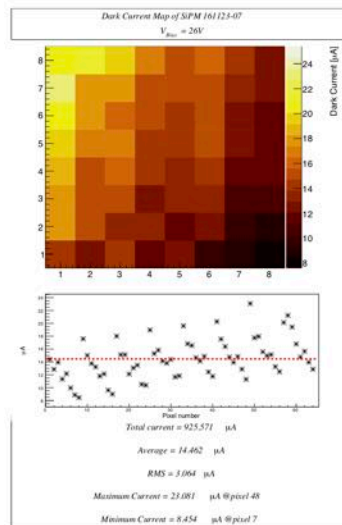
- Multiplexer was added and circuit was adjusted to choose the required resistance
- Voltage could be changed to pre-determined values through Raspberry Pi
- Scanning dark current through different voltages is possible
- An algorithm was devised to avoid heating issue - reads SiPM which are always the farthest from the previous SiPM



# RESULTS

## Accidental damage in CoSy

- Examples of the reports generated after the measurement
- By observing the patterns  $\Rightarrow$  location of the beam
- Identify defective or broken SiPM
- Observe the change in dark current after annealing in the oven

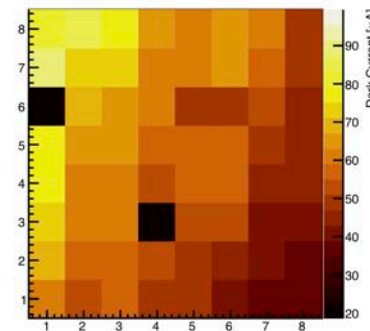


# RESULTS

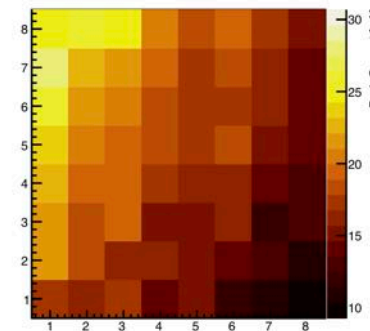
## Accidental damage in CoSy

- Examples of comparison reports generated
- Change in dark current can be visualised
- Examples:
  - 0 - 20 hours annealing
  - 0 - 266 hours annealing
  - 243 - 266 hours annealing

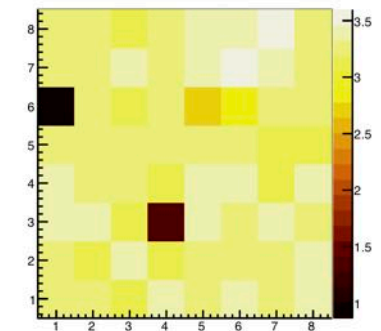
Dark Current Map: 161123-07 after Annealing (0h)



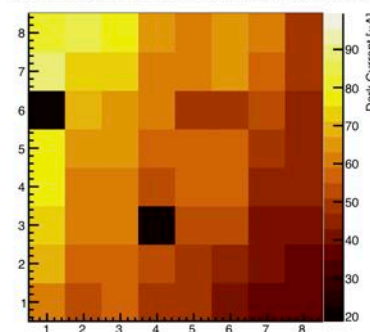
Dark Current Map: 161123-07 after Annealing (20h)



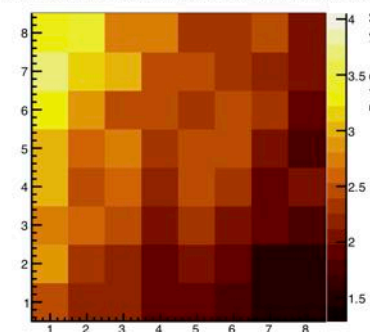
Relative Change of the Dark Current



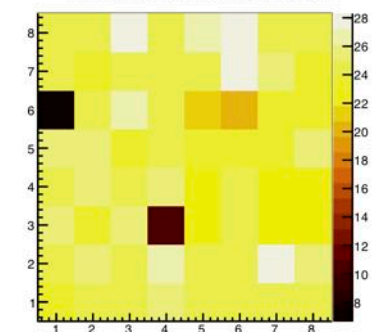
Dark Current Map: 161123-07 after Annealing (0h)



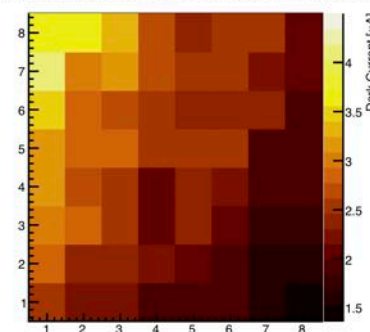
Dark Current Map: 161123-07 after Annealing (266h)



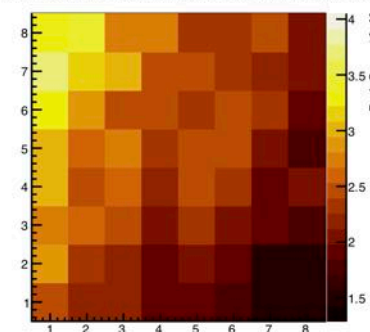
Relative Change of the Dark Current



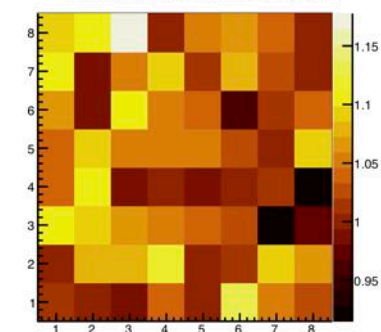
Dark Current Map: 161123-07 after Annealing (243h)



Dark Current Map: 161123-07 after Annealing (266h)



Relative Change of the Dark Current

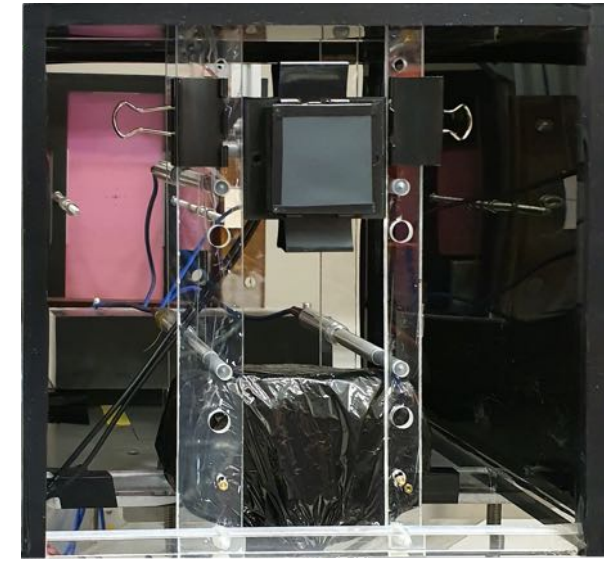




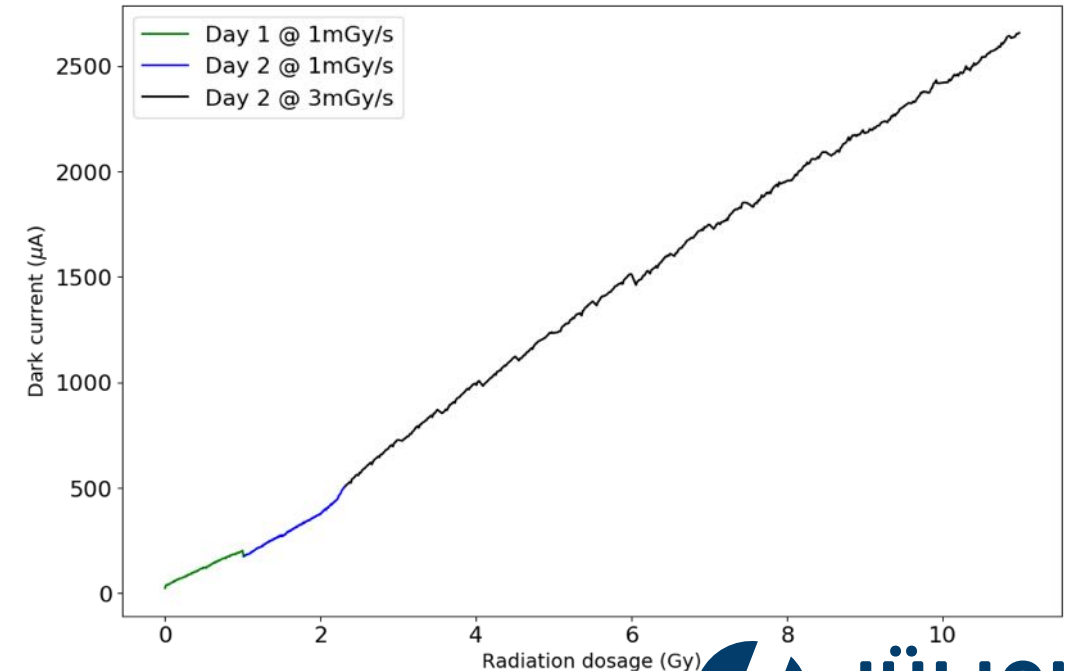
# RESULTS

## Investigating the radiation hardness of the SiPM arrays

- Healthy SiPM was exposed to totally of 11 Gy from Cyclotron
- Dark current was measured during irradiation and also when radiation was switched off
- Radiation film was placed on the SiPM to observe the radiation pattern and uniformity
- Live feed of the dark current was set up to observe the changes instantly
- Radiation damage with Cyclotron was similar to the damaged caused in the accident for the SiPMs in the second ring



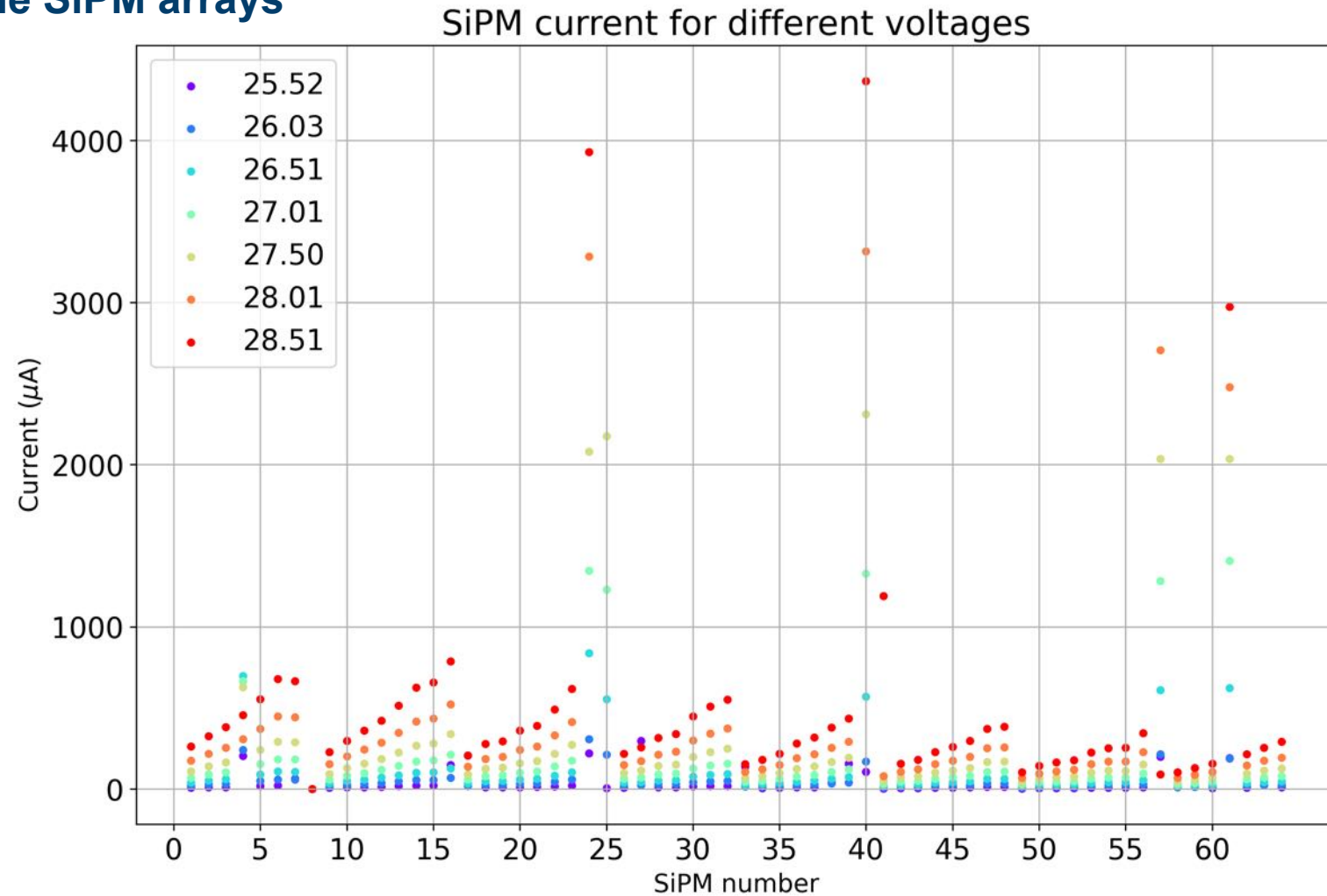
Dark current of SiPM on radiation



# RESULTS

## Investigating the radiation hardness of the SiPM arrays

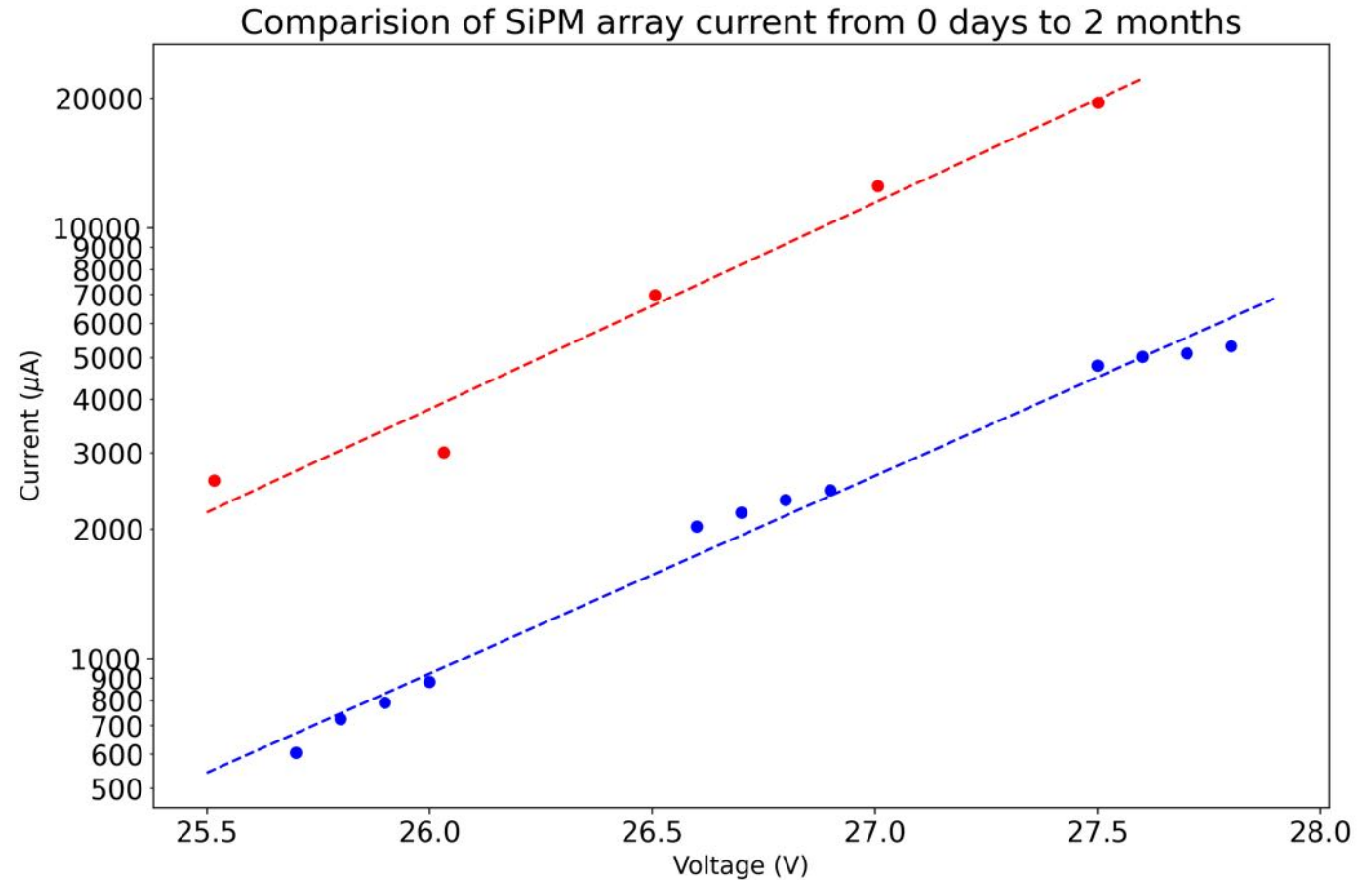
- Dark current of each SiPM in the matrix for different voltages is measured
- Increase in the dark current with increasing voltage can be observed



# RESULTS

## Investigating the radiation hardness of the SiPM arrays

- Dark current of the SiPM matrix for different voltages
- Change in dark current over the period of 2 months of annealing
- **Data** was recorded every 12 hours for a period of 7 days



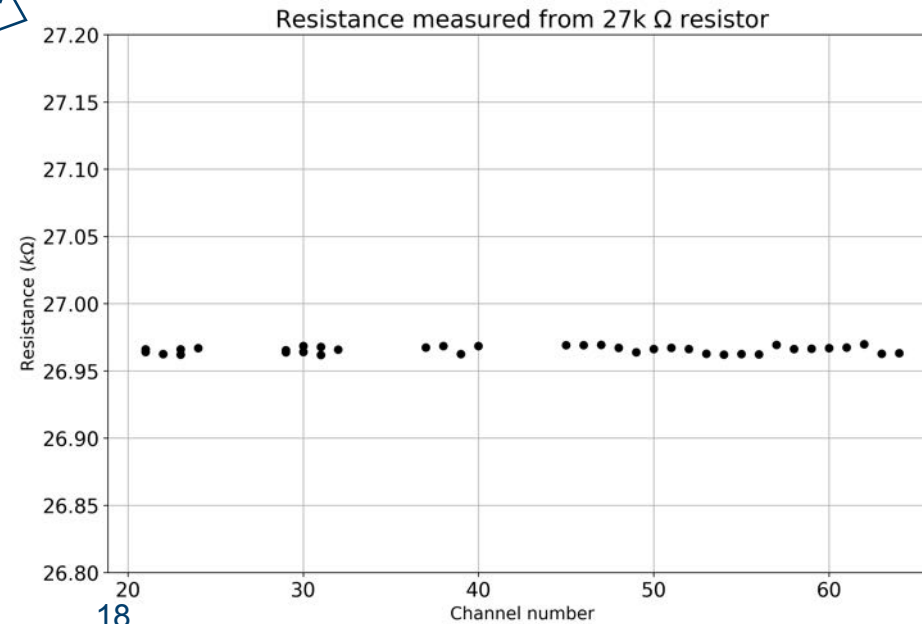
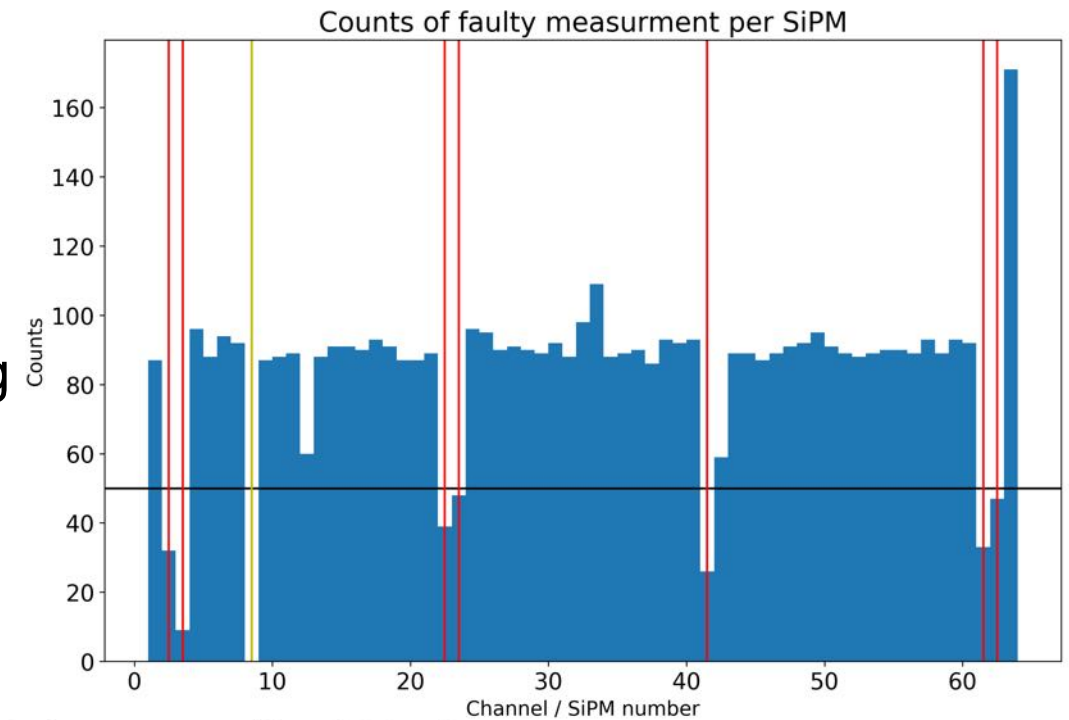
# CURRENT ISSUES

- Random jumps in the current recorded
- No pattern has been found yet
- \* Calibration of the setup was performed by replacing SiPM board with 27kΩ resistor

Voltage and current were measured at all times.  
Resistance of the resistor was calculated using

$$R = \frac{V}{I}$$

- Measuring dark current of the whole matrix gives comparable results but not individual SiPM results
- Voltage drift in the power supply



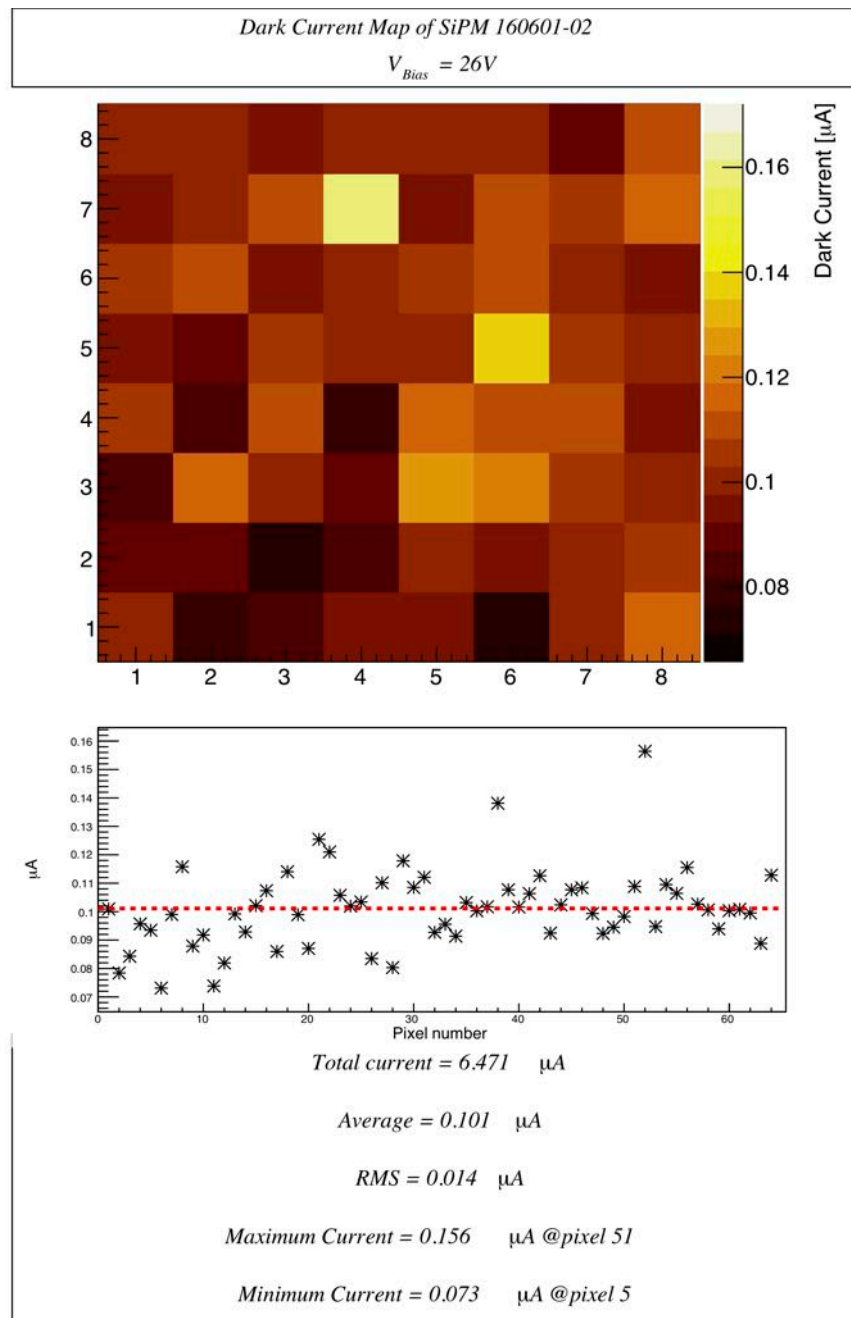
# FUTURE PLANS

- Identifying the root cause for jumps
- Adding an external reference to have much higher stability in supply voltage

Thank you

# BACK-UP

## Full report of 160601-02





# BACK-UP

## Full report of pattern plot

